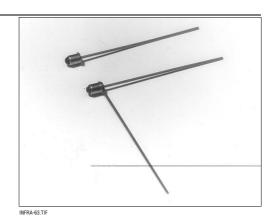
### Silicon Photodiode

### **FEATURES**

- Compact, metal can coaxial package
- 24° (nominal) acceptance angle
- Wide operating temperature range (- 55°C to +125°C)
- Mechanically and spectrally matched to SE1450 and SE1470 infrared emitting diodes



### DESCRIPTION

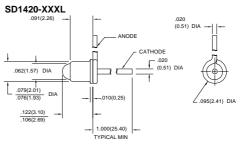
The SD1420 is a PN junction silicon photodiode mounted in a glass lensed metal can coaxial package. The package may have a tab or second lead welded to the can as an optional feature (SD1420-XXXL). Both leads are flexible and may be formed as required to fit various mounting configurations.

### **OUTLINE DIMENSIONS** in inches (mm)

 $\begin{array}{ccc} \text{Tolerance} & 3 \text{ plc decimals} & \pm 0.005 (0.12) \\ & 2 \text{ plc decimals} & \pm 0.020 (0.51) \end{array}$ 

# SD1420-XXX .091(2.26) ANODE CATHODE .062(1.57) DIA .076(1.93) DIA .122(3.10) .106(2.69) .100(25.40)

DIM\_10a.ds4



DIM\_10b.ds4

Honeywell

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

## Silicon Photodiode

### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Light Current	l <sub>L</sub>				μΑ	V <sub>R</sub> =20 V
SD1420-002, SD1420-002L		5.0				H=5 mW/cm <sup>2 (1)</sup>
Dark Current	Ι <sub>D</sub>			5.0	nA	V <sub>R</sub> =20 V
						H=0
Reverse Breakdown Voltage	$V_{BR}$	50			V	I <sub>R</sub> =10 μA
Angular Response (2)	Ø		24		degr.	I <sub>F</sub> =Constant
Rise And Fall Time	t <sub>r</sub> , t <sub>f</sub>		50		ns	V <sub>R</sub> =20 V
						R <sub>L</sub> =50 Ω

- Notes

  1. The radiation source is a tungsten lamp operating at a color temperature of 2870°K.

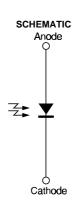
  2. Angular response is defined as the total included angle between the half sensitivity points.

### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted) Cathode Anode Voltage 75 mW (1) Power Dissipation Operating Temperature Range -55°C to 125°C -65°C to 150°C Storage Temperature Range Soldering Temperature (10 sec)

### Notes

Derate linearly from 25°C free-air temperature at the rate of 0.71 mW/°C.



## Silicon Photodiode

### SWITCHING TIME TEST CIRCUIT

Vcc 20 V Cathode H 10 μS

Anode

R 50 Ω

Polytonia

SWITCHING WAVEFORM

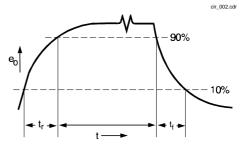


Fig. 1 Responsivity vs Angular Displacement

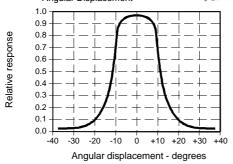


Fig. 2 Dark Current vs

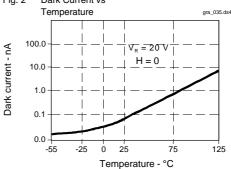
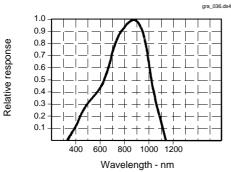


Fig. 3 Spectral Responsivity



All Performance Curves Show Typical Values

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Silicon Photodiode

